







1.0MHz STEP-UP DC-DC CONVERTER

Description

The PAM2401 is a high efficiency, current mode, fixed frequency, step-up DC/DC converter with true output disconnect and inrush current limiting. The device includes one 0.10Ω N-channel MOSFET switch and one 0.15Ω P-channel synchronous rectifier. This product has the ability to simply program the output voltage from 2.5V to 5.0V.The switching frequency is 1.0MHz, programmable current limit set by an external resistor from 1.0A to 3.0A with internal soft-start. When loading became light, the converter will automatically enter into PSM to improve the efficiency.

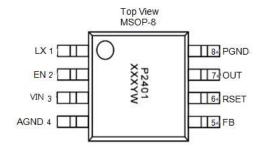
Quiescent current is only 150 μ A during Pulse Skip Mode operation, maximizing battery life in portable applications. Other features include : <1 μ A shutdown, anti-ringing control, Hiccup mode at short protection, over voltage protection and over temperature protection.

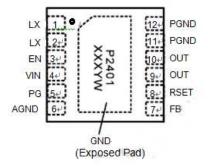
The PAM2401 is available in MSOP-8 and U-DFN3030-12 packages

Features

- Up to 95% Efficiency
- True Output Disconnect
- Inrush Current Limiting When Power On
- Output Current up to 1000mA at V_{IN} = 3V and V_{OUT} = 5.0V
- Fixed Frequency Operation Up to 1MHz
- 0.9V to 4.75V Input Range
- 2.5V to 5.0V Adjustable Output Voltage
- Guaranteed 1.0V Start-Up
- Programmable Current Limit
- Internal Soft-Start
- Internal Compensation
- Pulse Sipping Mode at Light Load Operation
- Hiccup Mode Short Protection
- Over Voltage Protection
- Over Temperature Protection
- <1µA Shutdown Current
- Power Good Indicator
- MSOP-8 and U-DFN3030-12 packages
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Pin Assignments





Applications

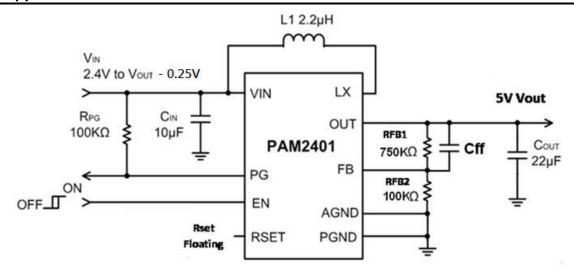
- Handheld Computers
- Cordless Phones
- GPS Receivers
- Battery Backup Supplies

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



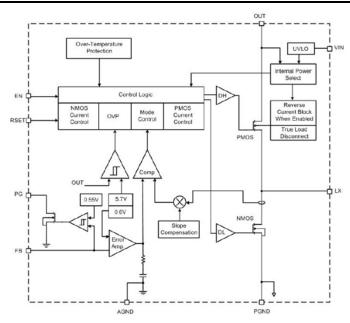
Typical Applications Circuit



Pin Descriptions

MSOP-8	U-DFN3030-12	Name	Function
1	1,2	LX	Switch Pin
2	3	EN	Enables Control Input.
3	4	VIN	Input Voltage Pin
	5	PG	Power Good Indicator Pin, Open Drain Output
4	6	AGND	Analog Ground
5	7	FB	Feedback Pin Internally Set to 0.6V.
6	8	RSET	Current Limit Setting
7	9,10	OUT	Output Pin
8	11,12	PGND	Power Ground
	Exposed Pad	EP	Thermal Pad of the Package. Can Be Connected to PGND

Functional Block Diagram





Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

These are stress ratings only and functional operation is not implied. Exposure to absolute maximum ratings for prolonged time periods may affect device reliability. All voltages are with respect to ground.

Parameter	Rating	Unit
Input Voltage	-0.3 to +6.0	V
SW Voltage	-0.3 to +6.0	V
SHDN, FB Voltage	-0.3 to +6.0	V
V _{OUT}	-0.3 to +6.0	V
Operating Temperature Range	-40 to +85	°C
Storage Temperature Range	-65 to +125	°C
Lead Temperature (Soldering, 10 sec)	300	°C

Recommended Operating Conditions (@T_A = +25°C, unless otherwise specified.)

Parameter	Rating	Unit
Ambient Temperature Range	-40 to +85	°C
Junction Temperature Range	-40 to +125	C

Thermal Information

Parameter	Package	Symbol	Max	Unit
Thermal Resistance	MSOP-8	0	75	
(Junction to Case)	U-DFN3030-12	Θ _{JC}	8.5	°C/W
Thermal Resistance	MSOP-8	Θ _{JC}	180	
(Junction to Ambient)	U-DFN3030-12		60	
Internal Dower Dissipation	MSOP-8	D	0.55	W
Internal Power Dissipation	U-DFN3030-12	P_{D}	1.66	VV





$\hline \textbf{Electrical Characteristics} \text{ (T}_{A} = +25^{\circ}\text{C, V}_{IN} = 3.3\text{V, V}_{OUT} = 5\text{V, L} = 2.2\mu\text{H, unless otherwise noted.)}$

PARAMETER	SYMBOL	Test Conditions	Min	Тур	Max	Units	
Input Voltage Dange		No load, V _O = 5V	0.9		4.75	V	
Input Voltage Range	V _{IN}	I _O =1A , V _O = 5V	2.7		4.75		
Minimum Startup Voltage	V _{STARTUP}	I _O = 0.1A, V _O = 3.3V		1		V	
Shutdown Supply Current	I _{SD}			0.1	1	μΑ	
Quiescent Current	Iq	No load, switching (measured with external feedback); V _O = 5V		150		μΑ	
Oscillator Frequency	fosc		0.8	1	1.2	MHz	
Maximum Duty Cycle	D _{MAX}			87.5		%	
Output-Voltage Adjust Range	Vo		2.5		5	V	
FB Regulation Voltage	V _{FB}	No Load	0.588	0.6	0.612	V	
Load Regulation	LDR	I _{OUT} = 1mA to 1000mA		2.5		%	
Line Regulation	LNR	V _O = 2.5V to 4.75V, I _O = 0.5A		0.3		%/V	
D : 0	Б	P MOSFET		150	250	mΩ	
Drain-Source On-State Resistance	R _{DS(ON)}	N MOSFET		100	170	mΩ	
		R_{SET} Floating or R_{SET} > 200K Ω		3		Α	
N-Channel Current Limit (Note)	I _{LIMIT}	R _{SET} = 100KΩ		1.5		Α	
		R _{SET} = 66KΩ		1		Α	
Pre-charge Current	I-Charge	V _{OUT} +0.5V < V _{IN}		500		mA	
Pre-charge Time	T-Charge	V _{OUT} +0.5V < V _{IN}		400		μs	
SW Leakage Current	ILSW		0.1		2	μA	
Power Good Threshold	VPG			92		%	
EN Threshold High	V_{H}	V _{IN} = 0.9V	0.8			V	
Liv Tillesilolu Filgii	V _H	V _{IN} = 3.3V	1.5			v v	
EN Threshold Low	VL	V _{IN} > 1.2V			0.2	V	
Over Temperature Threshold	TOTSD			160		°C	
Over Temperature Hysteresis	THYS			50		°C	

Note: N-Channel current limit is guaranteed by design.



Application Information

Output Voltage Set Equation

The output voltage of the PAM2401, V_{OUT} , is set by an external resistor divider from VOUT to ground as shown in figure 1. The divider tap is connected to the FB pin and the typical value of the voltage at the FB pin is 0.6V. The following equation is used to set the V_{OUT} : V_{OUT} = 0.6 (1+R1/R2) For example, if output voltage of 5V is needed, with a chosen R2 value of $100k\Omega$, the value of R1 can be calculated according to the equation, so a $750k\Omega$ resistor should be chosen for R1.

Inductor Selection

To select an inductor for use in PAM2401 applications, it is worth noting that the inductor current saturation rating should be larger than the possible peak inductor current to ensure proper operation, and should have low DCR (DC resistance). Using an inductor the saturation current of which is lower than required can cause a dramatic drop in the inductance and can decay the maximum output current levels severely. For most applications, the value of the inductor should be in the range ofs 1µH to 4.7µH. Its value is chosen based on the desired ripple current.

Larger value inductors result in lower ripple currents, and smaller value inductors result in higher ripple currents. A 1.5µH or 2.2µH inductor will be the best choice for most PAM2401 applications. The following equation can also help give a good approximate value for the inductor.

$$L = \frac{V I N x D}{\Delta I L x f}$$

D Duty Cycle=1- V_{IN}/V_{OUT} , F Switching Frequency = 1.0MHz, ΔIL Ripple Current in the Inductor, i.e., 20% to 40% of the maximum inductor current (Ip).

Output and Input Capacitor Selection Input Capacitor

At least a 10µF input capacitor is recommended to reduce the input ripple and switching noise for normal operating conditions, while a 10-22µF capacitor may be required for higher power and dynamic loads. Larger values and lower ESR (Equivalent Series Resistance) may be needed if the application require very low input ripple. It follows that ceramic capacitors are a good choice for applications. Note that the input capacitor should be located as close as possible to the IC.

Output Capacitor

A minimum output capacitor value of 22µF is recommended and may be increase to a larger value. The ESR of the output capacitor is important because it determines the peak to peak output voltage ripple by the following equation:

$$\Delta VOUT >> 2\Delta IL xRESR$$

Multilayer ceramic capacitors are an excellent choice as they have extremely low ESR and are available in small footprints.



Typical Performance Characteristics (T_A = +25°C, V_{IN} = 3.3V, V_{OUT} = 5V, unless otherwise noted.)

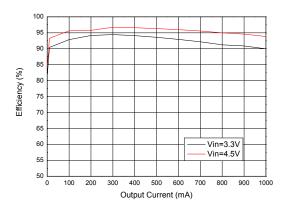


Figure 4 Efficiency vs. Output Current (MSOP-8)

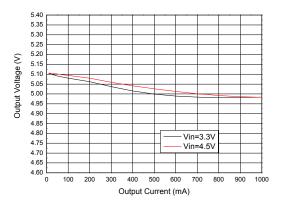


Figure 6 Output Voltage vs. Output Current

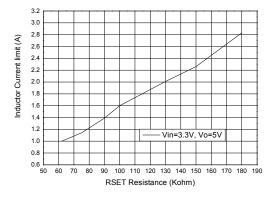


Figure 8 Inductor Current Limit vs. RSET Resistance

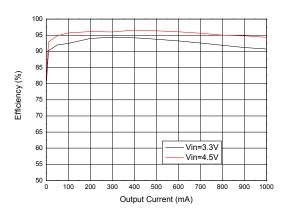


Figure 5 Efficiency vs. Output Current (U-DFN)

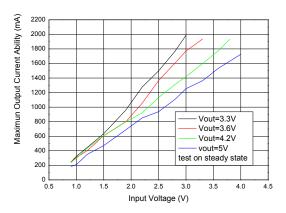


Figure 7 Maximum Output Current vs. Input Voltage

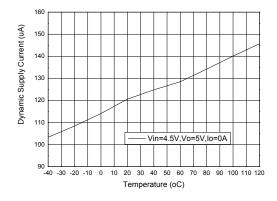


Figure 9 Dynamic Supply Current vs. Temperature





Typical Performance Characteristics (cont.) (T_A = +25°C, V_{IN} = 3.3V, V_{OUT} = 5V, unless otherwise noted.)

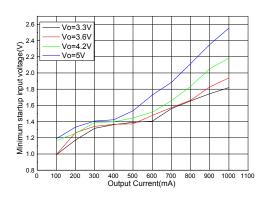


Figure 10 Minimum Startup Input Voltage vs. Output Current

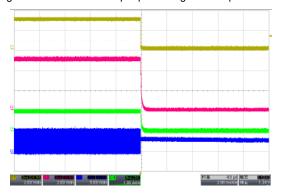


Figure 12 Enable Turn Off (I_O = 1A) (CH1: Enable; CH2:V_{OUT}; CH3:SW; CH4:lo)

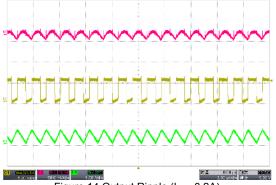


Figure 14 Output Ripple (I_O = 0.2A) (CH1: SW; CH2:V_{OUT}-AC; CH4:IL)



Figure 16 V_{OUT} Short Recovery ($I_O = 1A$) (CH2: V_{OUT}; CH3: IL)

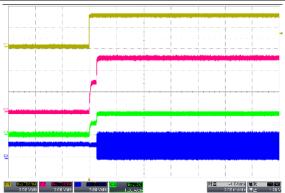


Figure 11 Enable Turn On $(I_O = 1A)$ (CH1: Enable; CH2: V_{OUT} ; CH3:SW; CH4: I_O)

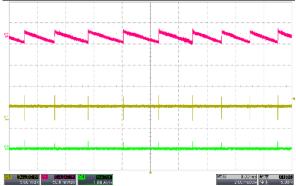


Figure 13 Output Ripple ($I_0 = 0\overline{A}$) (CH1:SW; CH2: V_{OUT-AC} ; CH4:IL)

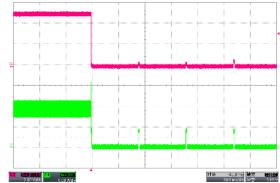
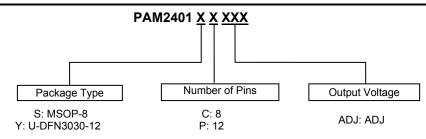


Figure 15 V_{OUT} Short Protection ($I_O = 1A$) (CH2: V_{OUT} ; CH3:IL)

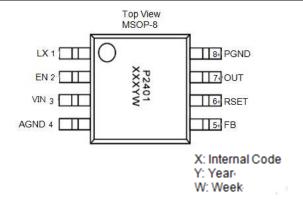


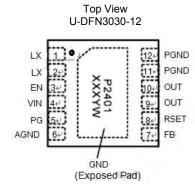
Ordering Information



Part Number	Marking	Package Type	Standard Package
PAM2401SCADJ	P2401 XXXYW	MSOP-8	2,500 units/ Tape & Reel
PAM2401YPADJ	P2401 XXXYW	U-DFN3030-12	3,000 units/ Tape & Reel

Marking Information



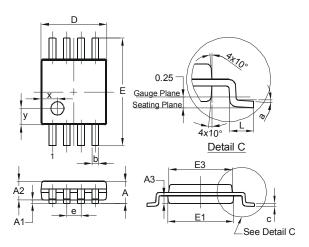




Package Outline Dimensions (All dimensions in mm.)

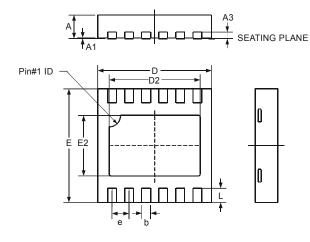
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

(1) MSOP-8



MSOP-8				
Dim	Min	Max	Тур	
Α	ı	1.10	-	
A1	0.05	0.15	0.10	
A2	0.75	0.95	0.86	
A3	0.29	0.49	0.39	
b	0.22	0.38	0.30	
С	0.08	0.23	0.15	
D	2.90	3.10	3.00	
Е	4.70	5.10	4.90	
E1	2.90	3.10	3.00	
E3	2.85	3.05	2.95	
е	ı	ı	0.65	
L	0.40	0.80	0.60	
а	0°	8°	4°	
X	-		0.750	
у	-		0.750	
All Dimensions in mm				

(2) U-DFN3030-12

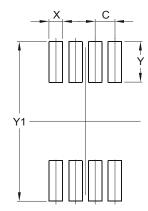


Ų	U-DFN3030-12					
Dim	Min	Max	Тур			
Α	0.57	0.63	0.60			
A1	0	0.05	0.02			
A3			0.15			
b	0.18	0.28	0.23			
D	2.90	3.10	3.00			
D2	2.30	2.50	2.40			
е			0.45			
Е	2.90	3.10	3.00			
E2	1.50	1.70	1.60			
٦	0.25	0.55	0.40			
All Dimensions in mm						

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

(1) MSOP-8



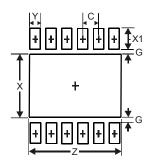
Dimensions	Value (in mm)
C	0.650
X	0.450
Y	1.350
Y1	5.300



Suggested Pad Layout (cont.)

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

(2) U-DFN3030-12



Dimensions	Value (in mm)
Z	2.60
G	0.15
Х	1.80
X1	0.60
Υ	0.28
С	0.45

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